



SLPS254A - FEBRUARY 2010-REVISED JULY 2010

# 30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17305Q5A

#### **FEATURES**

- **Optimized for 5V Gate Drive**
- Ultralow Q<sub>g</sub> and Q<sub>gd</sub>
- **Low Thermal Resistance**
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

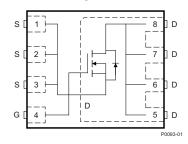
## **APPLICATIONS**

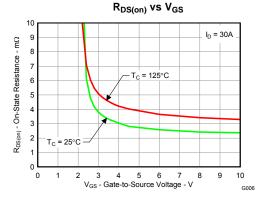
- **Notebook Point of Load**
- Point-of-Load Synchronous Buck in **Networking, Telecom and Computing Systems**

## **DESCRIPTION**

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.

## **Top View**





#### **PRODUCT SUMMARY**

V <sub>DS</sub>	Drain to Source Voltage	30	V			
$Q_g$	Gate Charge Total (4.5V) 14.1  Gate Charge Gate to Drain 3		Gate Charge Total (4.5V) 14.1			
$Q_{gd}$				nC		
		$V_{GS} = 3V$	3.9	mΩ		
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 4.5V 2.8		mΩ		
		V <sub>GS</sub> = 8V	2.4	mΩ		
$V_{GS(th)}$	Threshold Voltage	1.1		V		

#### **ORDERING INFORMATION**

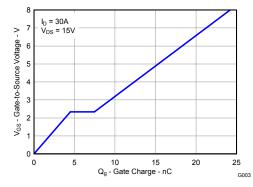
Device	Package	Media	Qty	Ship	
CSD17305Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel	

#### **ABSOLUTE MAXIMUM RATINGS**

T <sub>A</sub> = 2	5°C unless otherwise stated	VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	30	٧
$V_{GS}$	Gate to Source Voltage	+10 / -8	٧
	Continuous Drain Current, T <sub>C</sub> = 25°C	100	Α
I <sub>D</sub>	Continuous Drain Current <sup>(1)</sup>	29	Α
I <sub>DM</sub>	Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>	181	Α
$P_D$	Power Dissipation <sup>(1)</sup>	3.1	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, single pulse $I_D=78A,\ L=0.1mH,\ R_G=25\Omega$	304	mJ

- (1) Typical  $R_{\theta JA} = 40^{\circ}\text{C/W}$  on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%

## **GATE CHARGE**



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NexFET is a trademark of Texas Instruments.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics					
BV <sub>DSS</sub>	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30			V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 24V			1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.9	1.1	1.6	V
		$V_{GS} = 3V, I_D = 30A$		3.9	5.4	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 30A$		2.8	3.6	mΩ
		$V_{GS} = 8V, I_{D} = 30A$		2.4	3.4	mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A		139		S
Dynamic	: Characteristics				*	
C <sub>iss</sub>	Input Capacitance			2000	2600	pF
Coss	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz		1100	1430	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1101112		79	103	pF
R <sub>G</sub>	Series Gate Resistance			1	2	Ω
Qg	Gate Charge Total (4.5V)			14.1	18.3	nC
Q <sub>gd</sub>	Gate Charge Gate to Drain	V <sub>DS</sub> = 15V,		3		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	I <sub>D</sub> = 30A		4.5		nC
Q <sub>g(th)</sub>	Gate Charge at Vth			2.2		nC
Q <sub>oss</sub>	Output Charge	V <sub>DS</sub> = 13.5V, V <sub>GS</sub> = 0V		27		nC
t <sub>d(on)</sub>	Turn On Delay Time			8.9		ns
t <sub>r</sub>	Rise Time	$V_{DS} = 15V, V_{GS} = 4.5V, I_{D} = 30A$		16.5		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$R_G = 2\Omega$		20		ns
t <sub>f</sub>	Fall Time			7.9		ns
Diode Cl	haracteristics					
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 30A, V <sub>GS</sub> = 0V		0.85	1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> = 13.5V, I <sub>F</sub> = 30A,		34		nC
t <sub>rr</sub>	Reverse Recovery Time	di/dt = 300A/μs		27		ns

## THERMAL CHARACTERISTICS

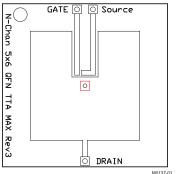
(T<sub>A</sub> = 25°C unless otherwise stated)

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			1.3	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (1) (2)			50	°C/W

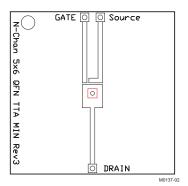
 $R_{\theta JC}$  is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB.  $R_{\theta JC}$  is specified by design, whereas  $R_{\theta JA}$  is determined by the user's board design. Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.

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Max  $R_{\theta JA} = 50^{\circ} C/W$  when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max  $R_{\theta JA} = 120^{\circ} C/W$  when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

# TYPICAL MOSFET CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

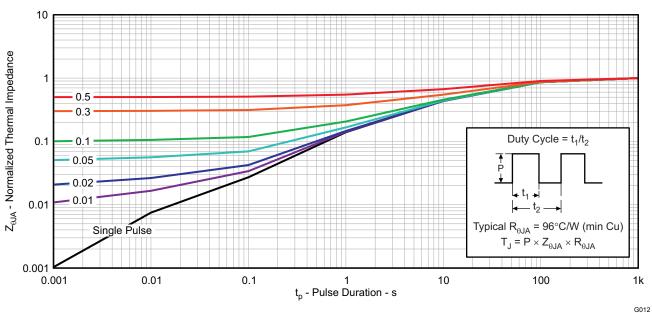


Figure 1. Transient Thermal Impedance

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# **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

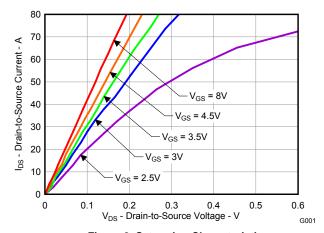


Figure 2. Saturation Characteristics

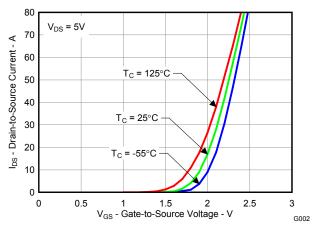


Figure 3. Transfer Characteristics

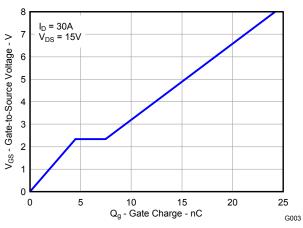


Figure 4. Gate Charge

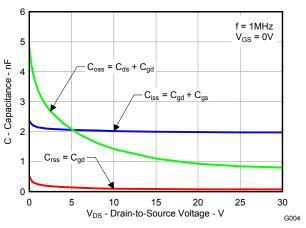


Figure 5. Capacitance

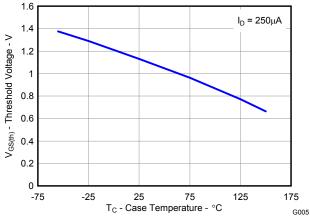


Figure 6. Threshold Voltage vs. Temperature

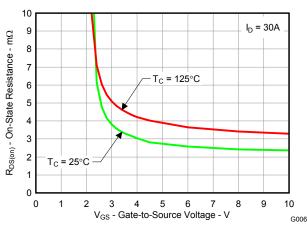


Figure 7. On-State Resistance vs. Gate to Source Voltage



# **TYPICAL MOSFET CHARACTERISTICS (continued)**

(T<sub>A</sub> = 25°C unless otherwise stated)

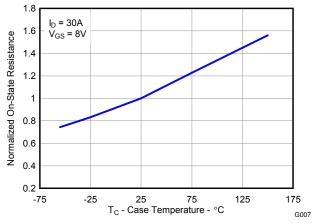


Figure 8. Normalized On-State Resistance vs. Temperature

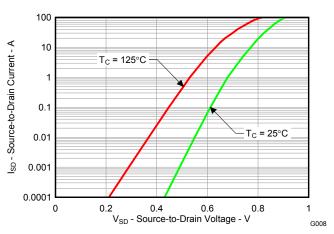


Figure 9. Typical Diode Forward Voltage

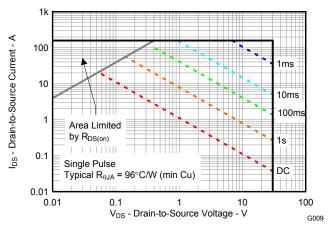


Figure 10. Maximum Safe Operating Area

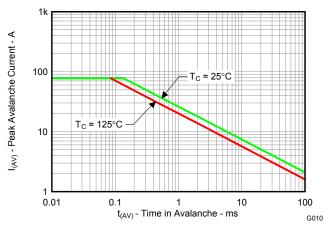


Figure 11. Single Pulse Unclamped Inductive Switching

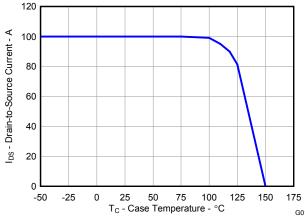
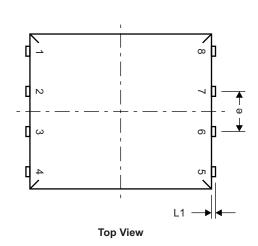


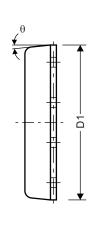
Figure 12. Maximum Drain Current vs. Temperature



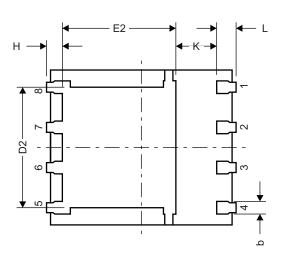
# **MECHANICAL DATA**

# **Q5A Package Dimensions**





Side View



**Bottom View** 

θ E1 = E Front View

M0135-01

DIM	MILLIMETERS						
DIM	MIN	NOM	MAX				
Α	0.90	1.00	1.10				
b	0.33	0.41	0.51				
С	0.20	0.25	0.34				
D1	4.80	4.90	5.00				
D2	3.61	3.81	4.02				
Е	5.90	6.00	6.10				
E1	5.70	5.75	5.80				
E2	3.38	3.58	3.78				
е	1.17	1.27	1.37				
Н	0.41	0.56	0.71				
K	1.10						
L	0.51	0.61	0.71				
L1	0.06	0.13	0.20				
θ	0°		12°				

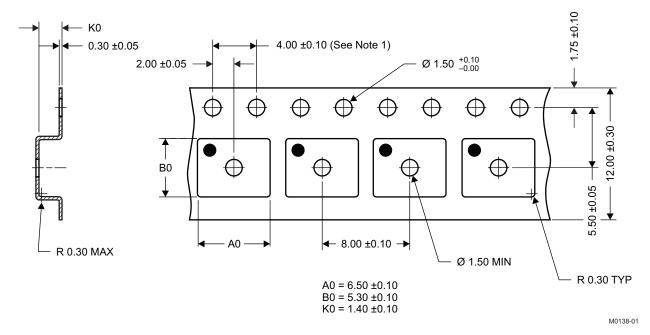


Recommended PCB Pattern						
F6 — F1 —	F7					
F10	4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4					

DIM	MILLIN	IETERS	INC	HES
DIIVI	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

# **Q5A Tape and Reel Information**



#### Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

# SLPS254A - FEBRUARY 2010-REVISED JULY 2010



# **REVISION HISTORY**

C	hanges from Original (February 2010) to Revision A	Page
•	Updated the Q5A Package Dimensions table. DIM c MAX was 0.30, DIM D2 MAX was 3.96, DIM e MIN was blank MAX was blank, DIM H NOM was 0.51 MAX was 0.61	6
•	Deleted Note 6 from the Q5A Tape and Reel Information - "MSL1 260°C (IR and convection) PbF reflow compatible"	7
•	Deleted the Package Marking Information section	<b>7</b>

# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



## \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD17305Q5A	SON	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD17305Q5A	SON	DQJ	8	2500	340.0	340.0	38.0

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